## Surface Mount Fast Recovery Rectifier



## Features

- Low profile package
- Ideal for automated placement
- Glass passivated chip junction
- High forward surge capability
- Fast reverse recovery time
- Meets MSL level 1, per J-STD-020, LF maximum peak of $260^{\circ} \mathrm{C}$


## Typical Applications

For use in high frequency rectification of power supplies, inverters, converters, and freewheeling diodes for consumer, and telecommunication.

## Mechanical Data

- Package: SMAF

Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free

- Terminals: Tin plated leads, solderable per J-STD-002 and JESD22-B102
- Polarity: Cathode line denotes the cathode end
-Maximum Ratings ( $\mathrm{Ta}=25^{\circ} \mathrm{C}$ Unless otherwise specified)

| PARAMETER | SYMBOL | UNIT | F2AF | F2BF | F2DF | F2GF | F2JF | F2KF | F2MF |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Device marking code |  |  | F2AF | F2BF | F2DF | F2GF | F2JF | F2KF | F2MF |
| Repetitive peak reverse voltage | VRRM | V | 50 | 100 | 200 | 400 | 600 | 800 | 1000 |
| Average rectified output current @60Hz sine wave, resistance load, TL (Fig.1) | 10 | A |  |  |  | 2.0 |  |  |  |
| Surge(non-repetitive)forward current $@ 60 \mathrm{~Hz}$ half-sine wave, 1 cycle, $\mathrm{Ta}=25^{\circ} \mathrm{C}$ | IFSM | A |  |  |  | 50 |  |  |  |
| Storage temperature | Tstg | ${ }^{\circ} \mathrm{C}$ | $-55 \sim+150$ |  |  |  |  |  |  |
| Junction temperature | Tj | ${ }^{\circ} \mathrm{C}$ | $-55 \sim+150$ |  |  |  |  |  |  |

■Electrical Characteristics ( $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ Unless otherwise specified)

| PARAMETER | SYMBOL | UNIT | TEST CONDITIONS | F2AF | F2BF | F2DF | F2GF | F2JF | F2KF | F2MF |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Maximum instantaneous forward voltage drop per diode | VF | V | $\mathrm{IFM}=2.0 \mathrm{~A}$ | 1.3 |  |  |  |  |  |  |
| Maximum reverse recovery time | $t_{r}$ | ns | $\begin{gathered} \mathrm{I}_{\mathrm{F}}=0.5 \mathrm{~A}, \mathrm{I}_{\mathrm{R}}=1.0 \mathrm{~A}, \\ \mathrm{I}_{\mathrm{n}}=0.25 \mathrm{~A} \end{gathered}$ | 150 |  |  |  | 250 | 500 |  |
| Maximum DC reverse current |  |  | $\mathrm{T}=25^{\circ} \mathrm{C}$ | 5.0 |  |  |  |  |  |  |
| per diode @ VRM=VRRM |  |  | Ta $=125^{\circ} \mathrm{C}$ | 100 |  |  |  |  |  |  |

F2AF THRU F2MF

■Thermal Characteristics ( $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ Unless otherwise specified)

| PARAMETER | SYMBOL | UNIT | F2AF | F2BF | F2DF | F2GF | F2JF | F2KF | F2MF |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Thermal resistance | $R$ RJ- $\mathrm{A}^{(1)}$ | ${ }^{\circ} \mathrm{C} M$ | $65^{1)}$ |  |  |  |  |  |  |
|  | R日J-L ${ }^{(1)}$ |  | $20^{11}$ |  |  |  |  |  |  |

Note:
(1) Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with $0.2^{\prime \prime} \times 0.2^{\prime \prime}(5.0 \mathrm{~mm} \times 5.0 \mathrm{~mm})$ copper pad areas

## - Characteristics (Typical)



FIG.5: Diagram of circuit and Testing wave form of reverse recovery time


## -Ordering Information (Example)

| PREFERED P/N | PACKING <br> CODE | UNIT WEIGHT(g) | MINIMUM <br> PACKAGE(pcs) | INNER BOX <br> QUANTITY(pcs) | OUTER CARTON <br> QUANTITY(pcs) | DELIVERY <br> MODE |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| F2AF-F2MF | F1 | Approximate 0.034 | 3000 | 12000 | 96000 | 7 " reel |
| F2AF-F2MF | F2 | Approximate 0.034 | 10000 | 20000 | 160000 | 13 " reel |
| F2AF-F2MF | F3 | Approximate 0.034 | 10000 | 20000 | 120000 | 13 " reel |
| F2AF-F2MF | F4 | Approximate 0.034 | 7500 | 15000 | 120000 | 13 reel |

## ■ Outline Dimensions



| SMAF |  |  |
| :---: | :---: | :---: |
| Dim | Min | Max |
| A | 2.40 | 2.80 |
| B | 1.35 | 1.45 |
| C | 3.40 | 3.60 |
| D | 4.40 | 4.80 |
| E | 1.05 | 1.25 |
| F | 0.50 | 1.00 |
| G | 0.15 | 0.22 |

## ■ Suggested pad layout



| SMAF |  |
| :---: | :---: |
| Dim | Millimeters |
| P1 | 6.50 |
| P2 | 4.00 |
| P3 | 1.50 |
| Q1 | 2.50 |
| Q2 | 1.70 |

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